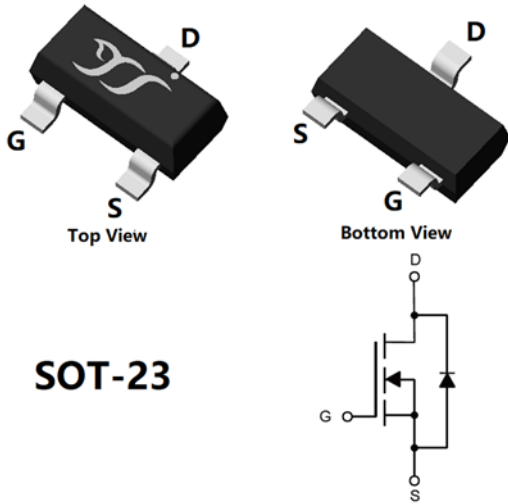


## N-Channel Enhancement Mode Field Effect Transistor



**SOT-23**

### Product Summary

- $V_{DS}$  600V
- $I_D$  100mA
- $R_{DS(ON)}$ ( at  $V_{GS}=10V$ )  $<260\Omega$

### General Description

- High density cell design for low  $R_{DS(ON)}$
- High Speed switching
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

### Applications

- Battery protection
- Load switch
- Power management

### ■ Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter		Symbol	Limit	Unit	
Drain-source Voltage		$V_{DS}$	600	V	
Gate-source Voltage		$V_{GS}$	$\pm 15$	V	
Continuous Drain Current (Note 1,2)	Steady-State	$I_D$	$T_A=25^\circ\text{C}, V_{GS}=10\text{V}$	100	mA
			$T_A=100^\circ\text{C}, V_{GS}=10\text{V}$	63	
Pulsed Drain Current	$T_C=25^\circ\text{C}, t_p=100\mu\text{s}$		$I_{DM}$	400	mA
Total Power Dissipation (Note 1,2)	Steady-State	$P_D$	$T_A=25^\circ\text{C}$	2	W
			$T_A=100^\circ\text{C}$	0.4	
Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~+150	$^\circ\text{C}$	

### ■ Thermal resistance

Parameter		Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient (Note 2)	Steady-State	$R_{\theta JA}$	52	62.5	$^\circ\text{C/W}$

### ■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJL001N60AJ	F2	01N60.	3000	30000	120000	7" reel



# YJL001N60AJ

## ■ Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
<b>Static Parameter</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> =250μA	600	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =600V, V <sub>GS</sub> =0V	-	-	1	μA
		V <sub>DS</sub> =600V, V <sub>GS</sub> =0V, T <sub>J</sub> =150°C	-	-	100	
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±15V, V <sub>DS</sub> =0V	-	-	±100	nA
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> =250μA	1.0	1.6	2.5	V
Static Drain-Source On-Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =100mA	-	176	260	Ω
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =100mA, V <sub>GS</sub> =0V	-	-	1.2	V
Gate resistance	R <sub>G</sub>	f=1MHz	-	11	-	Ω
Maximum Body-Diode Continuous Current	I <sub>S</sub>		-	-	100	mA
<b>Dynamic Parameters</b>						
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=200KHz	-	35.7	-	pF
Output Capacitance	C <sub>oss</sub>		-	4.6	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	3.1	-	
<b>Switching Parameters</b>						
Total Gate Charge	Q <sub>G</sub>	V <sub>GS</sub> =10V, V <sub>DS</sub> =480V, I <sub>D</sub> =100mA	-	2.2	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	0.2	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	0.6	-	
Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>F</sub> =100mA, di/dt=100A/us	-	0.07	-	nC
Reverse Recovery Time	t <sub>rr</sub>		-	250	-	ns
Turn-on Delay Time	t <sub>D(on)</sub>	V <sub>GS</sub> =10V, V <sub>DD</sub> =300V, I <sub>D</sub> =100mA R <sub>GEN</sub> =25Ω	-	32.6	-	ns
Turn-on Rise Time	t <sub>r</sub>		-	50.4	-	
Turn-off Delay Time	t <sub>D(off)</sub>		-	67.8	-	
Turn-off fall Time	t <sub>f</sub>		-	251.7	-	

### Note:

- The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
- The value of R<sub>θJA</sub> is measured with the device mounted on the 40mm\*40mm\*1.1mm single layer FR-4 PCB board with 1 in<sup>2</sup> pad of 2oz. Copper, in the still air environment with T<sub>A</sub> =25°C. The maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.



## Typical Electrical and Thermal Characteristics Diagrams

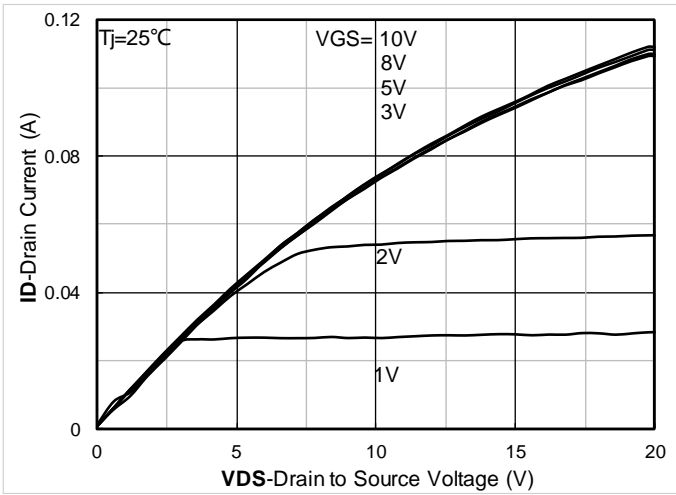


Figure 1. Output Characteristics

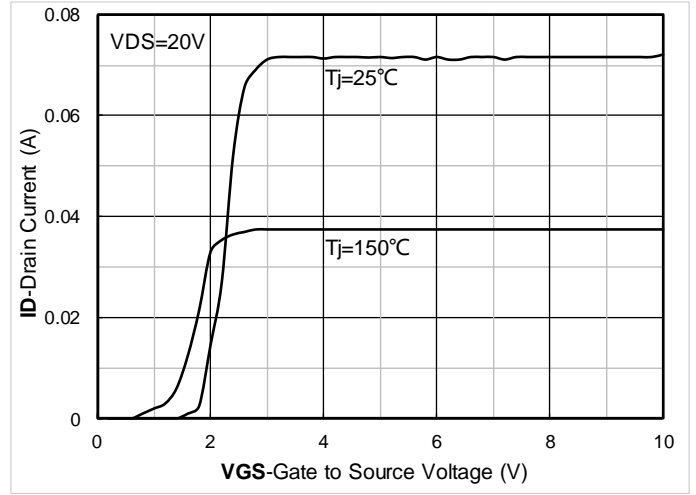


Figure 2. Transfer Characteristics

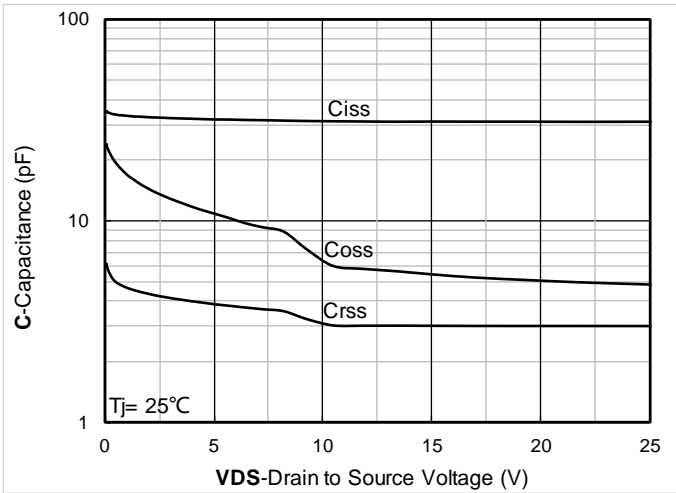


Figure 3. Capacitance Characteristics

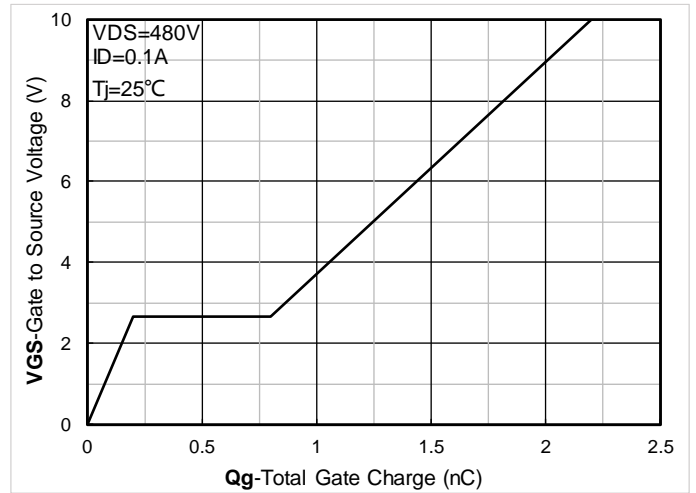


Figure 4. Gate Charge

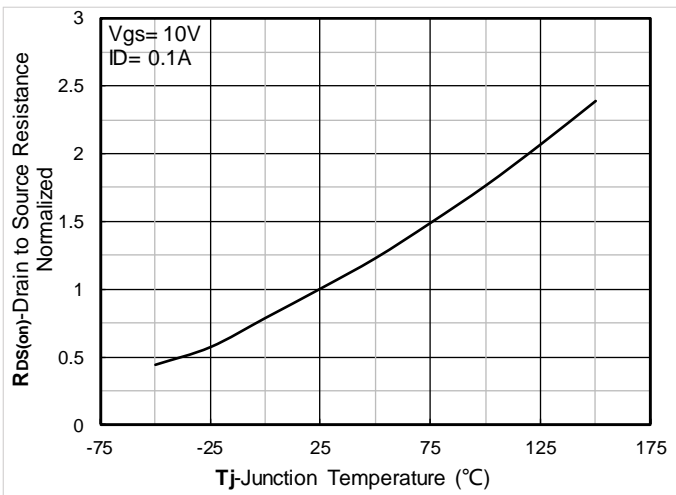


Figure 5. Normalized On-Resistance

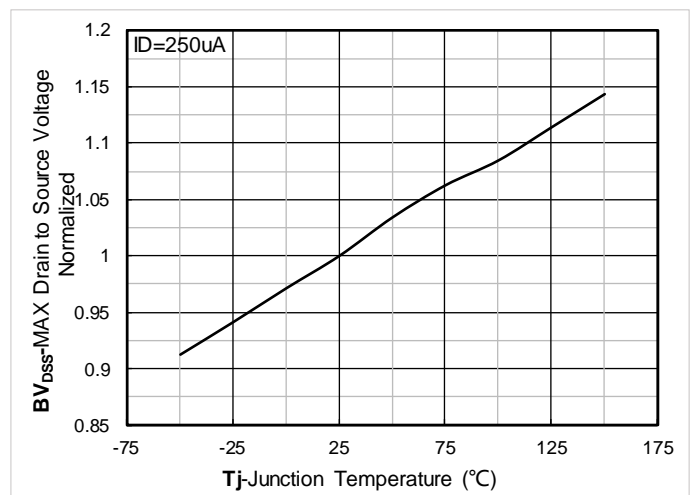


Figure 6. Normalized breakdown voltage



# YJL001N60AJ

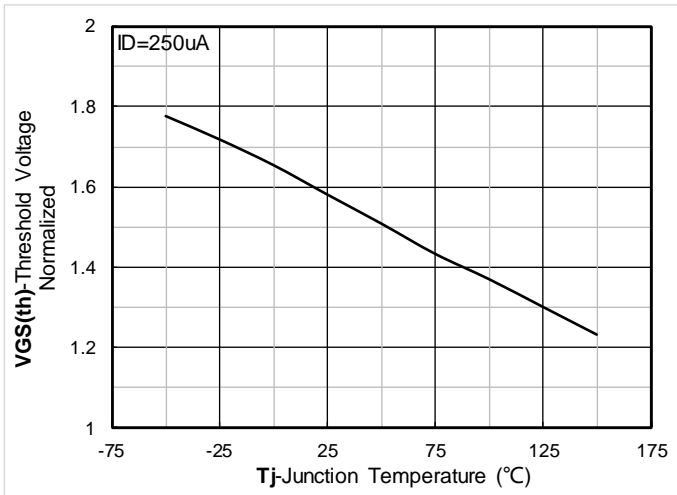


Figure 7. Normalized Threshold voltage

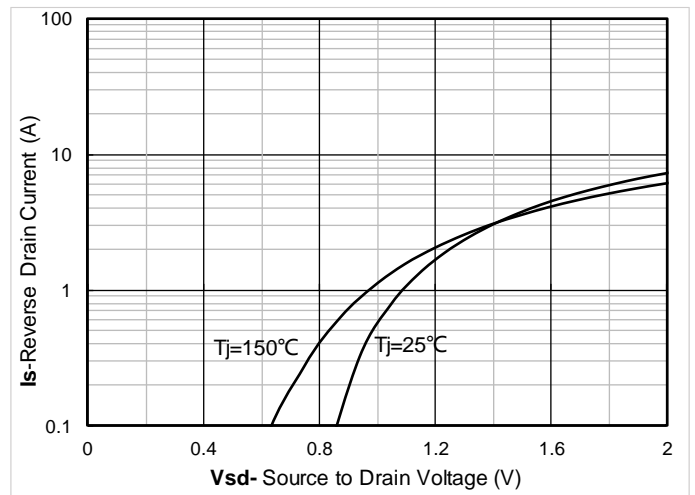


Figure 8. Forward characteristics of reverse diode

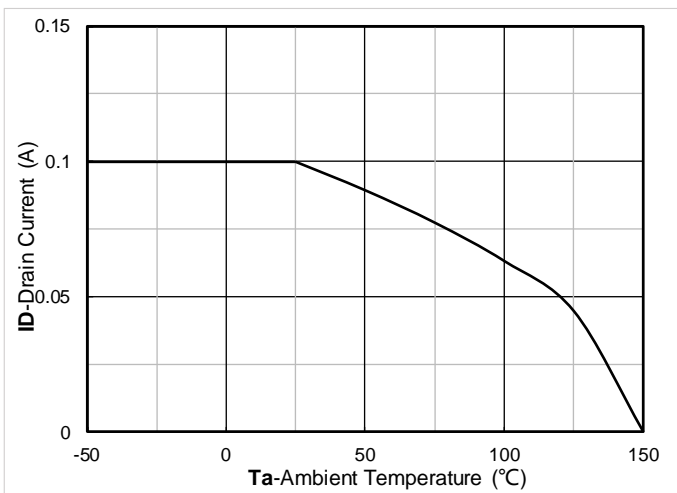


Figure 9. Current dissipation diode

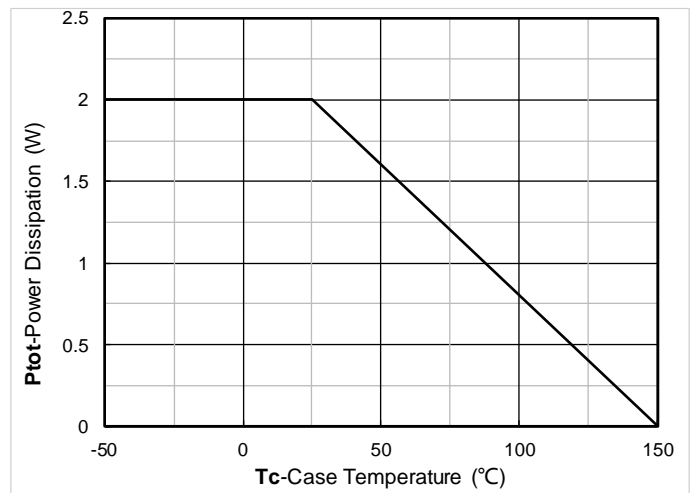
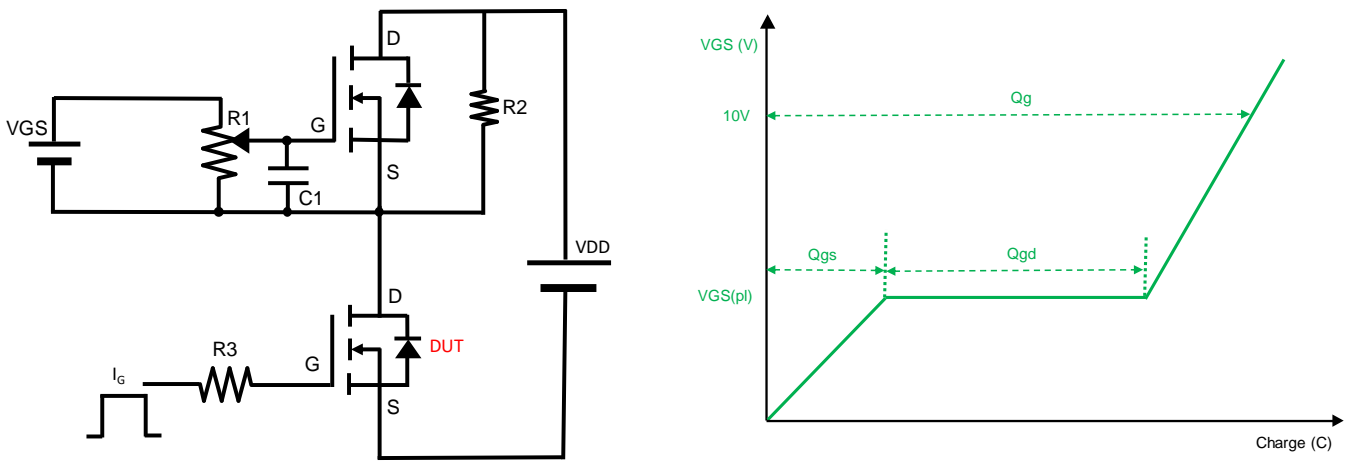
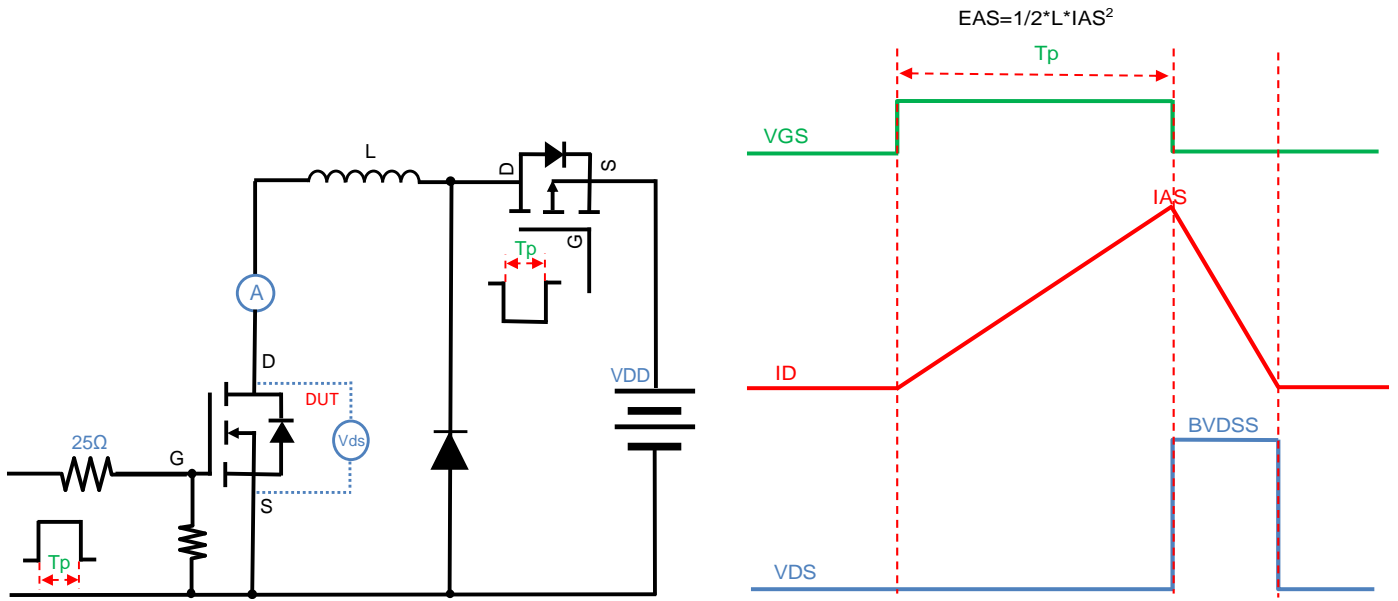


Figure 10. Power dissipation

## ■ Test Circuits & Waveforms



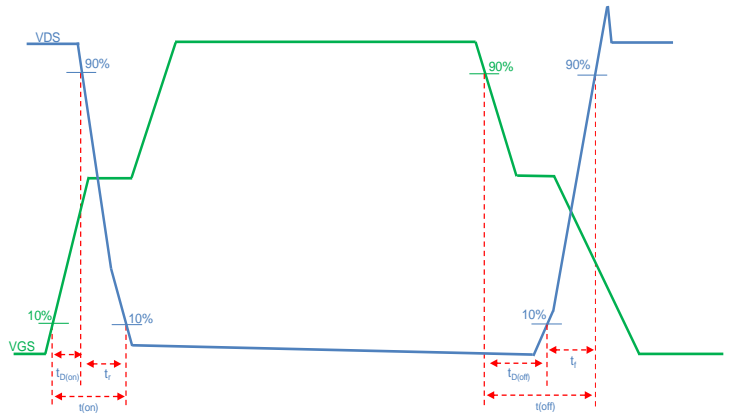
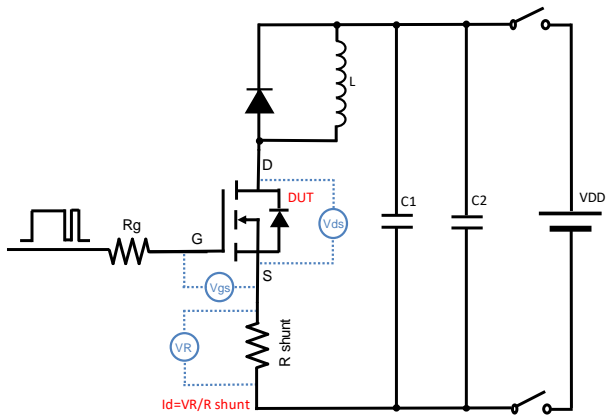


Figure C. Resistive Switching Test Circuit & Waveform

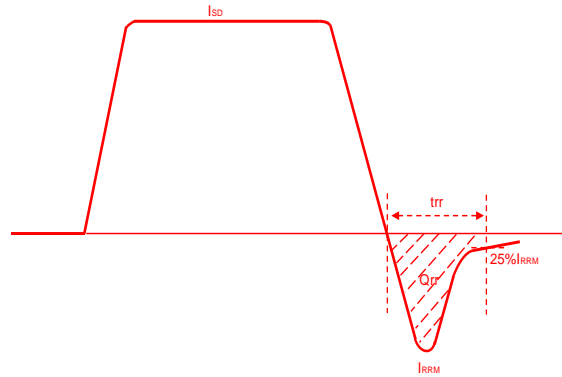
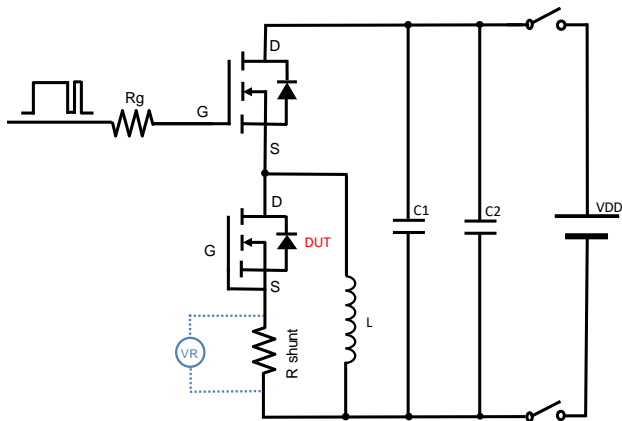
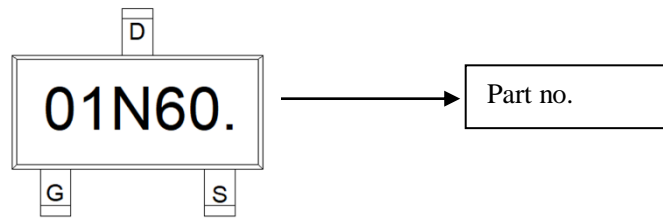


Figure D. Diode Recovery Test Circuit & Waveform



■Marking



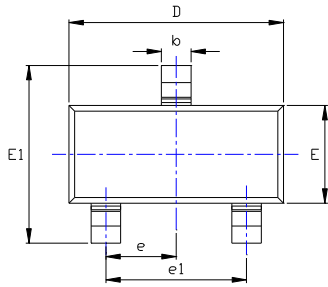
Note:

1. All marking is at middle of the product body
2. All marking is in laser printing
3. 01N60. is part no.
4. Body color: Black

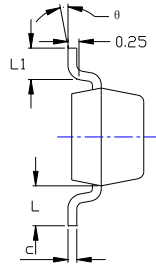


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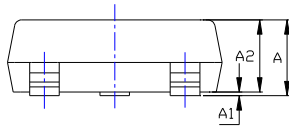
## ■ SOT-23 Package information



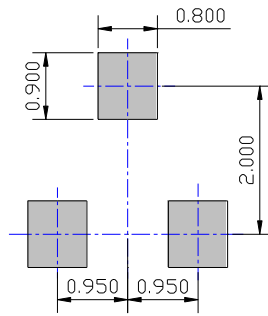
TOP VIEW



SIDE VIEW



SIDE VIEW



UNIT: mm

SUGGESTED SOLDER PAD LAYOUT

SYMBOL	DIMENSIONS			
	INCHES		Millimeter	
	MIN.	MAX.	MIN.	MAX.
A	0.035	0.045	0.900	1.150
A1	0.000	0.004	0.000	0.100
A2	0.035	0.041	0.900	1.050
b	0.012	0.020	0.300	0.500
c	0.004	0.008	0.100	0.200
D	0.110	0.118	2.800	3.000
E	0.047	0.055	1.200	1.400
E1	0.089	0.100	2.250	2.550
e	0.037TYP		0.950TYP	
e1	0.071	0.079	1.800	2.000
L	0.022REF		0.550REF	
L1	0.012	0.020	0.300	0.500
θ	0°	8°	0°	8°

NOTE:  
 1.PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.  
 2.TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.  
 3.THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.





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